

isc Silicon NPN Power Transistor

DESCRIPTION

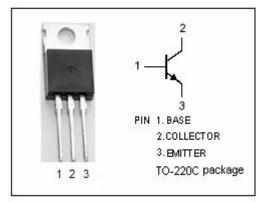
- · Low Collector Saturation Voltage
 - : V_{CE(sat)}= 1.0V(Max)@ I_C= 2A
- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 80V (Min)
- Wide Area of Safe Operation
- Complement to Type 2SA1634
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

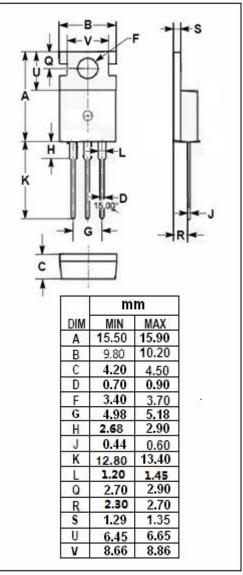
APPLICATIONS

• Designed for audio and general purpose applications

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	V		
V _{CEO}	Collector-Emitter Voltage	80	V	
V _{EBO}	Emitter-Base Voltage	6	V	
l _C	Collector Current-Continuous	Α		
I _{CM}	Collector Current-Peak	Α		
P _C	Collector Power Dissipation @ T _C =25℃	40	W	
	Collector Power Dissipation @ T _a =25℃	2		
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature Range	age Temperature Range -55~150		







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2SC4007

ELECTRICAL CHARACTERISTICS

Tc=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 50 μ A; I _E = 0	100			V
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 25mA; I _B = 0	80			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 50 μ A; I _C = 0	6			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 2A; I _B = 0.2A			1.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	Ic= 2A; I _B = 0.2A			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 100V; I _E = 0			10	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = 6V; I _C = 0			10	μА
h _{FE}	DC Current Gain	I _C = 1A; V _{CE} = 4V	100		500	
f _T	Current-Gain—Bandwidth Product	I _E = -0.2A ; V _{CE} = 12V		10		MHz
Сов	Output Capacitance	I _E =0 ; V _{CB} = 10V; f _{test} = 1MHz		60		pF

♦ h_{FE} classifications

Е	F	G	
100-200	160-320	250-500	

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